



Typical Applications

The HMC843LC4B is ideal for:

- RF ATE Applications
- Broadband Test & Measurement
- Serial Data Transmission up to 45 Gbps
- Digital Logic Systems up to 25 GHz
- NRZ-to-RZ Conversion

Features

Supports High Data Rates: up to 45 Gbps Differential & Singe-Ended Operation Fast Rise and Fall Times: 10 / 10 ps Low Power Consumption: 530 mW

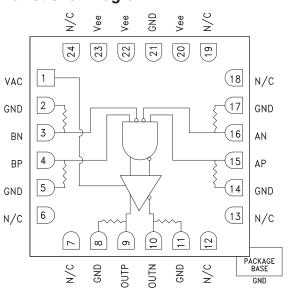
Programmable Differential Output Voltage Swing:

200 - 900 mV

Single Supply: -3.3V

24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC843LC4B is an AND/NAND/OR/NOR function designed to support data transmission rates of up to 45 Gbps, and clock frequencies as high as 25 GHz. The HMC843LC4B may be easily configured to provide any of the following logic functions:

AND, NAND, OR and NOR. The HMC843LC4B also features an output level control pin, VAC, which allows for loss compensation or for signal level optimization.

All input signals to the HMC843LC4B are terminated with 50 Ohms to ground on-chip, and may be either AC or DC coupled. The differential outputs of the HMC843LC4B may be either AC or DC coupled. Outputs can be connected directly to a 50 Ohms-to-ground terminated system, while DC blocking capacitors should be used if the terminating system is 50 Ohms to a non-ground DC voltage. The HMC843LC4B operates from a single -3.3V DC supply, and is available in a ceramic RoHS compliant 4x4 mm SMT package.

Electrical Specifications, $T_A = +25$ °C, Vee = -3.3V

| Parameter | Conditions | Min. | Тур. | Max | Units | |
|--|---|-------|-------|-------|-------|--|
| Power Supply Voltage | ±5 % Tolerance | -3.47 | -3.3 | -3.13 | V | |
| Power Supply Current | VAC = -0.4V | 145 | 160 | 175 | mA | |
| Output Amplitude Control Voltage (VAC) | | -1.7 | -0.4 | -0.1 | V | |
| Maximum Data Rate | | 45 | | | Gbps | |
| Maximum Clock Rate | | 25 | | | GHz | |
| Laurent Amarikanska | Single-ended, peak-to-peak | 100 | | 300 | | |
| Input Amplitude | Differential, peak-to-peak 100 1000 | | mVp-p | | | |
| Input High Voltage | | -0.5 | | 0.5 | V | |
| Input Low Voltage | | -1 | | 0 | V | |
| Output Amplitude | Differential, peak-to-peak @ 40 Gbps | 200 | | 900 | mVp-p | |



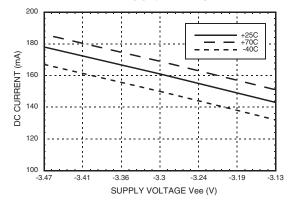


Electrical Specifications, (continued)

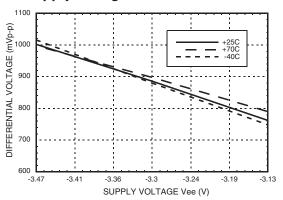
| Parameter | Conditions | Min. | Тур. | Max | Units |
|-------------------------------|--------------------|------------|------|-----|--------|
| Output High Voltage | | VAC = -0.3 | -70 | | mV |
| Output Low Voltage | | VAC = -0.3 | -570 | | mV |
| Input Return Loss | Frequency < 25 GHz | | 10 | | dB |
| Output Return Loss | Frequency < 25 GHz | | 10 | | dB |
| Deterministic Jitter, Jd [1] | | | 3 | | ps, pp |
| Additive Random Jitter Jr [2] | | | 0.2 | | ps rms |
| Rise Time, tr [1] | | | 10 | | ps |
| Fall Time, tf [1] | | | 10 | | ps |
| Propagation Delay, td | | | 10 | | ps |

^[1] A Input: 40 Gbps PRBS 2²³-1 pattern, 150 mVp-p single-ended, B Input: 40 Gbps 10101... pattern, 200 mVp-p single-ended

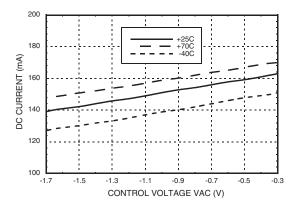
DC Current vs. Supply Voltage [1] [2]



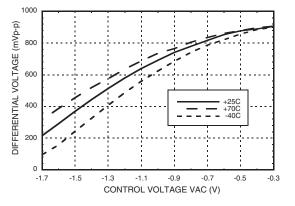
Differential Output Swing vs. Supply Voltage [1] [2]



DC Current vs. VAC [2]



Differential Output Swing vs. VAC [2]



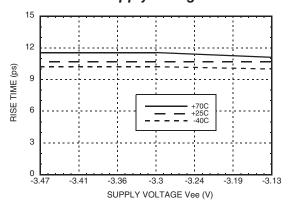
[1] VAC = -0.4V [2] Input data rate: 40 Gbps PRBS 2^{23} -1

^[2] Random jitter is measured with 40 Gbps 10101... pattern

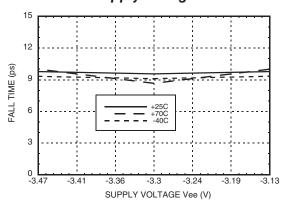




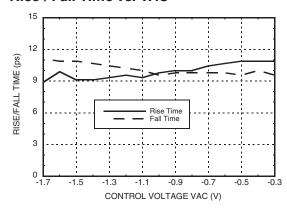
Rise Time vs. Supply Voltage [1][2][3]



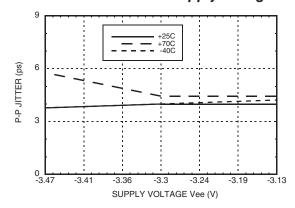
Fall Time vs. Supply Voltage [1][2][3]



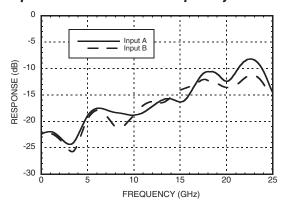
Rise / Fall Time vs. VAC [1][2][3]



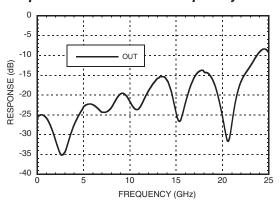
Peak-to-Peak Jitter vs. Supply Voltage [1][2][3][4]



Input Return Loss vs. Frequency [1][5]



Output Return Loss vs. Frequency [1][5]



[1] VAC = -0.4V[4] Source jitter was not deembeded

[2] Input data rate: 40 Gbps PRBS 223-1

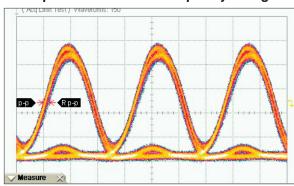
[3] Data was taken at single ended output

[5] Device measured on evaluation board with single-ended time domain gating.





40 Gbps RZ Differential Output Eye Diagram



| | Me | easurements | | |
|------------|----------|-------------|----------|----------------|
| | Current | Min | Max | Total Meas. |
| Eye Amp | 832 mV | 830 mV | 833 mV | 48 |
| Rise Time | 10.67 ps | 10.67 ps | 10.67 ps | 48 |
| Fall Time | 10.00 ps | 9.67 ps | 10.00 ps | 48 |
| p-p Jitter | 3.667 ps | 3.000 ps | 3.667 ps | 48 |

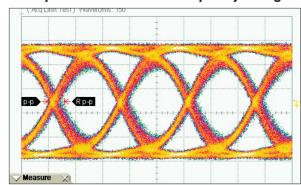
Time Scale: 10 ps/div Amplitude Scale: 200 mV/div

Test Conditions:

Vee = -3.3V, VAC = -0.4V

A Input: 40 Gbps PRBS 2²³-1 pattern, 150 mVp-p single-ended B Input: 40 Gbps 10101... pattern, 200 mVp-p single-ended

40 Gbps NRZ Differential Output Eye Diagram



| Measurements | | | | |
|--------------|----------|----------|----------|----------------|
| | Current | Min | Max | Total Meas. |
| Eye Amp | 769 mV | 768 mV | 770 mV | 48 |
| Rise Time | 14.00 ps | 13.78 ps | 14.22 ps | 48 |
| Fall Time | 12.67 ps | 12.22 ps | 12.89 ps | 48 |
| p-p Jitter | 6.000 ps | 4.889 ps | 6.000 ps | 48 |

Time Scale: 10 ps/div Amplitude Scale: 200 mV/div

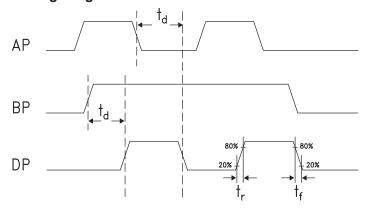
Test Conditions:

 $Vee = -3.3V, \ VAC = -0.4V$

A Input: 40 Gbps PRBS 2²³-1 pattern, 150 mVp-p single-ended

B Input: BP = 0V, BN = -0.3V

Timing Diagram



Truth Table

| Input | | Outputs |
|---|---------------------------------|---------|
| A | В | D |
| L | L | L |
| L | Н | L |
| Н | L | L |
| Н | Н | Н |
| Notes: A = AP - AN B = BP - BN D = DP - DN | H - Logic High L - Logic Low | |





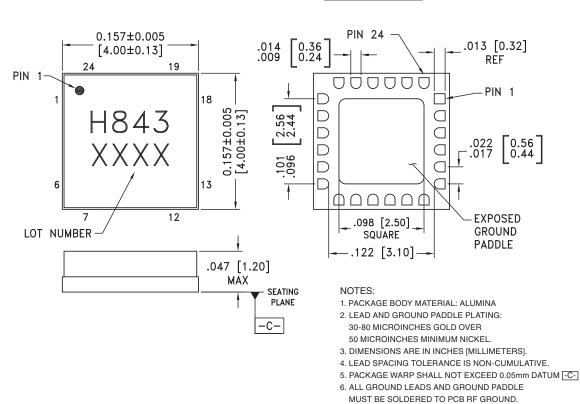
Absolute Maximum Ratings

| Power Supply Voltage (Vee) | -3.7V to +0.5V |
|--|-----------------|
| Input Voltage | -1.3V to +0.5V |
| Channel Temperature | 125°C |
| Continuous Pdiss (T = 85°C) (derate 24.42 mW/°C above 85°C) | 0.98 W |
| Thermal Resistance (channel to ground paddle) | 40.95 °C/W |
| Storage Temperature | -65°C to +125°C |
| Operating Temperature | -40°C to +70°C |
| Output Amplitude Control Voltage (VAC) | -2.3V to +0.5V |



Outline Drawing

BOTTOM VIEW







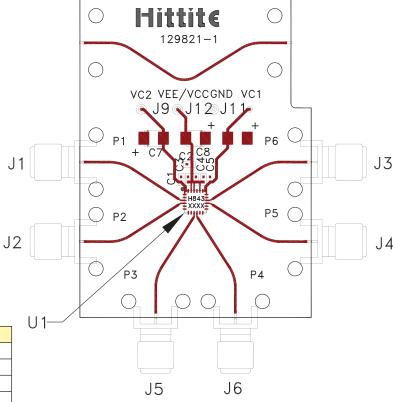
Pin Descriptions

| 1 VAC Output amplitude control voltage 2, 5, 8, 11, 14, 17, 21 Package Base 3, 4 BN, BP Differential (BP-BN) or single-ended (BP) data inputs GND VAC Output amplitude control voltage VAC Output amplitude control voltage |
|---|
| 14, 17, 21 Package Base Signal and supply grounds GND GND 50 0 |
| 500} |
| Vee |
| The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally. |
| 9, 10 OUTP, OUTN AND/OR/NAND/NOR outputs GND 600 OUTP OUTN Vee |
| 15, 16 AP, AN Differential (AP-AN) or single-ended (AP) data inputs AN, AP |
| Vee |





Evaluation PCB



| Item | Description |
|------|-------------|
| J1 | BN |
| J2 | BP |
| J3 | AN |
| J4 | AP |
| J5 | OUTP |
| J6 | OUTN |
| J9 | VAC |
| J11 | GND |
| J12 | Vee |

List of Materials for Evaluation PCB 128921 [1]

| Item | Description |
|--------------|----------------------------------|
| J1 - J6 | K Connector |
| J9, J11, J12 | DC Pin |
| C1, C3 - C5 | 1000pF Capacitor, 0402 Pkg. |
| C2 | 0.1 μF Capacitor, 0402 Pkg. |
| C7, C8 | 4.7 μF Capacitor, Tantalum |
| U1 | HMC843LC4B AND / NAND / OR / NOR |
| PCB [2] | 129821 Evaluation Board |

^[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. The exposed metal package base must be connected to Vee. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.





Application Circuit

